PTO-1449 (Modified) 3 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT	ATTY. DOCKET NO. RA043D2DC	SERIAL NUMBER 09/545,648
	APPLICANT(S) FARMWALD ET AL.	
	FILING DATE April 10, 2000	GROUP ART UNIT 2781

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